

## HIGH CURRENT NPN SILICON TRANSISTOR

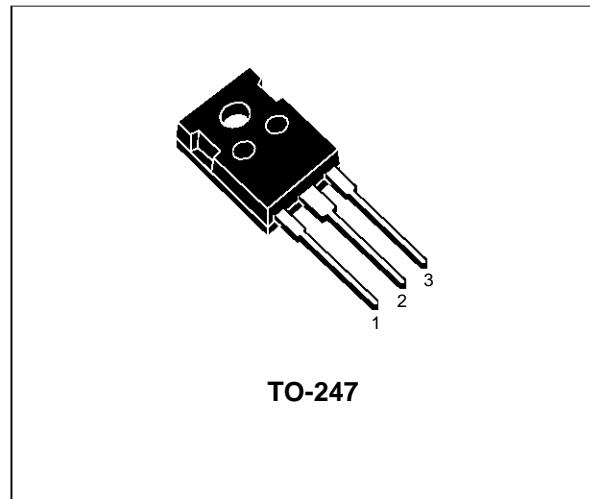
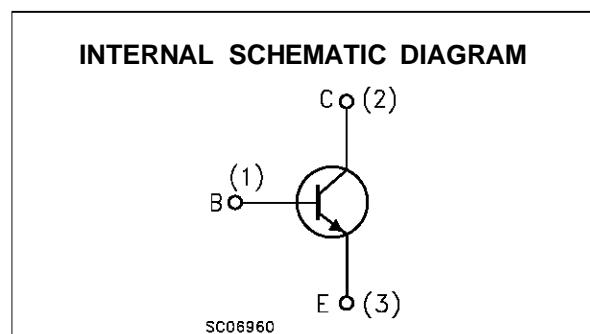
- SGS-THOMSON PREFERRED SALESTYPE
- NPN TRANSISTOR

**APPLICATIONS:**

- MOTOR CONTROL
- HIGH FREQUENCY AND EFFICIENCY CONVERTERS

**DESCRIPTION**

High current, high speed transistor suited for power conversion applications, high efficiency converters and motor controls.


**TO-247**

**ABSOLUTE MAXIMUM RATINGS**

Symbol	Parameter	Value	Unit
$V_{CES}$	Collector-Emitter Voltage ( $V_{BE} = 0$ )	500	V
$V_{CEO}$	Collector-Emitter Voltage ( $I_B = 0$ )	250	V
$V_{EBO}$	Emitter-Base Voltage ( $I_C = 0$ )	7	V
$I_E$	Emitter-Current	60	A
$I_{EM}$	Emitter Peak Current ( $t_p < 5\text{ms}$ )	70	A
$I_B$	Base Current	15	A
$I_{BM}$	Base Peak Current ( $t_p < 5\text{ms}$ )	18	A
$P_{tot}$	Total Dissipation at $T_c \leq 25^\circ\text{C}$	180	W
$T_{stg}$	Storage Temperature	-65 to 150	°C
$T_j$	Max. Operating Junction Temperature	150	°C

For PNP type voltage and current values are negative.

**THERMAL DATA**

$R_{thj-case}$	Thermal Resistance Junction-case	MAX	0.7	$^{\circ}\text{C/W}$
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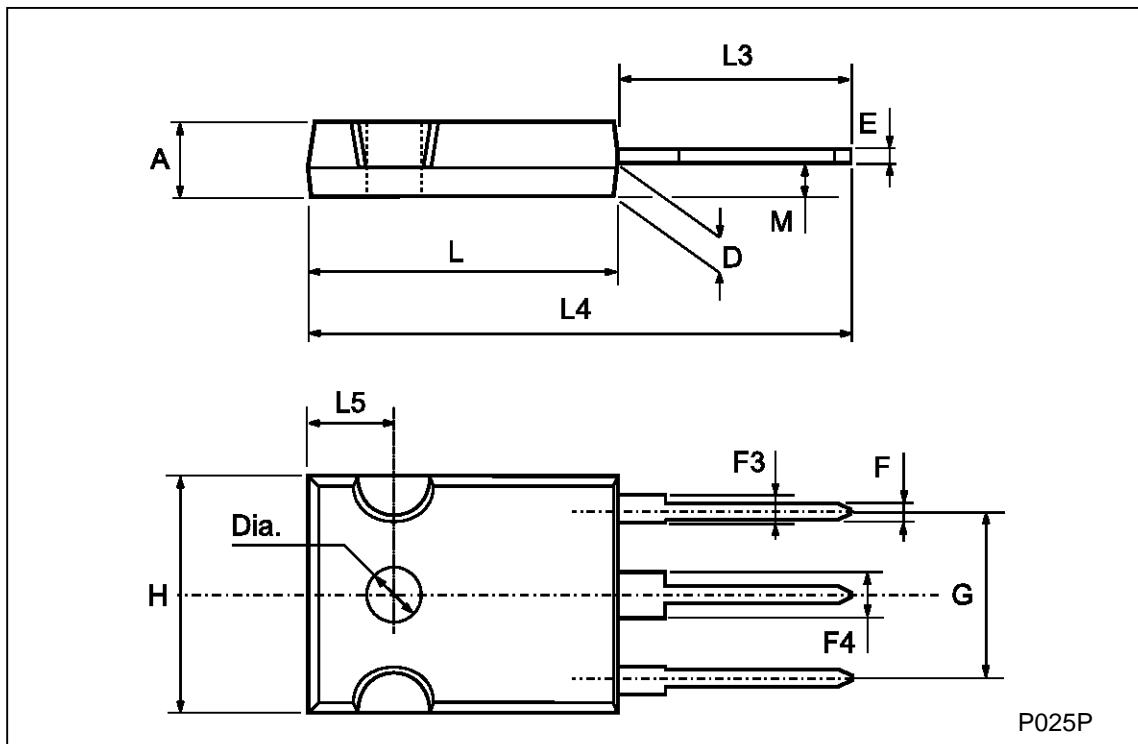
**ELECTRICAL CHARACTERISTICS** ( $T_{case} = 25 \text{ }^{\circ}\text{C}$  unless otherwise specified)

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Unit
$I_{CES}$	Collector Cut-off Current ( $V_{BE} = -1.5\text{V}$ )	$V_{CE} = 450\text{ V}$ $V_{CE} = 450\text{ V}$ $T_C = 100\text{ }^{\circ}\text{C}$			50 1	$\mu\text{A}$ $\text{mA}$
$I_{EBO}$	Emitter Cut-off Current ( $I_C = 0$ )	$V_{EB} = 5\text{ V}$			50	$\mu\text{A}$
$V_{CES}$	Collector-Emitter Breakdown Voltage ( $V_{EB} = 0$ )	$I_C = 5\text{ mA}$	500			$\text{V}$
$V_{EBO}$	Emitter-Base Breakdown Voltage ( $I_C = 0$ )	$I_E = 50\text{ mA}$	7			$\text{V}$
$V_{CEO(sus)*}$	Collector-Emitter Sustaining Voltage ( $I_B=0$ )	$I_C = 200\text{ mA}$	250			$\text{V}$
$V_{CE(sat)*}$	Collector-Emitter Saturation Voltage	$I_C = 60\text{ A}$ $I_B = 15\text{ A}$ $I_C = 60\text{ A}$ $I_B = 15\text{ A}$ $T_C = 100\text{ }^{\circ}\text{C}$		0.8 1.1	1 1.5	$\text{V}$ $\text{V}$
$V_{BE(sat)*}$	Base-Emitter Saturation Voltage	$I_C = 60\text{ A}$ $I_B = 15\text{ A}$ $I_C = 60\text{ A}$ $I_B = 15\text{ A}$ $T_C = 100\text{ }^{\circ}\text{C}$			1.9 2	$\text{V}$ $\text{V}$
$h_{FE}*$	DC Current Gain	$I_C = 60\text{ A}$ $V_{CE} = 3\text{ V}$ $I_C = 60\text{ A}$ $V_{CE} = 3\text{ V}$ $T_C = 100\text{ }^{\circ}\text{C}$ $I_C = 5\text{ A}$ $V_{CE} = 3\text{ V}$	9 6		65	
$t_s$ $t_f$	RESISTIVE LOAD Storage Time Fall Time	$I_C = 50\text{ A}$ $V_{CC} = 250\text{ V}$ $I_{B1} = -I_{B2} = 10\text{ A}$		1.2 250	1.4 300	$\mu\text{s}$ $\text{ns}$

\* Pulsed: Pulse duration = 300  $\mu\text{s}$ , duty cycle 1.5 %

## TO-247 MECHANICAL DATA

DIM.	mm			inch		
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
A	4.7		5.3	0.185		0.209
D	2.2		2.6	0.087		0.102
E	0.4		0.8	0.016		0.031
F	1		1.4	0.039		0.055
F3	2		2.4	0.079		0.094
F4	3		3.4	0.118		0.134
G		10.9			0.429	
H	15.3		15.9	0.602		0.626
L	19.7		20.3	0.776		0.779
L3	14.2		14.8	0.559	0.413	0.582
L4		34.6			1.362	
L5		5.5			0.217	
M	2		3	0.079		0.118
Dia	3.55		3.65	0.140		0.144



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